UNR5227

Silicon NPN epitaxial planer type

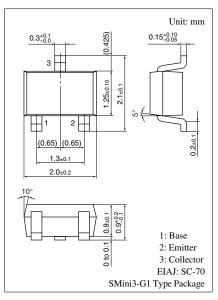
For muting circuit

■ Features

- Low collector to emitter saturation voltage V_{CE(sat)}
- Built-in resistor, allowing reduction of the number of parts.

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage | V_{CBO} | 30 | V |
| Collector to emitter voltage | V _{CEO} | 20 | V |
| Emitter to base voltage | V_{EBO} | 5 | V |
| Collector current | I_C | 600 | mA |
| Total power dissipation | P_{T} | 150 | mW |
| Junction temperature | T _j | 150 | °C |
| Storage temperature | T_{stg} | -55 to +150 | °C |



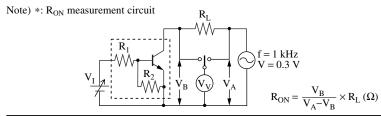
Marking Symbol: FW

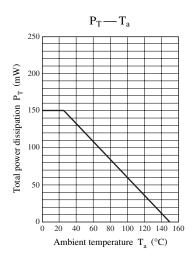
Internal Connection

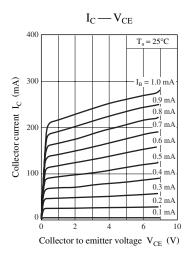
$$\begin{array}{c} R_1 \\ (6.8 \text{ k}\Omega) \\ \text{B} \circ \longrightarrow \\ R_2 \\ (6.8 \text{ k}\Omega) \longrightarrow \text{E} \end{array}$$

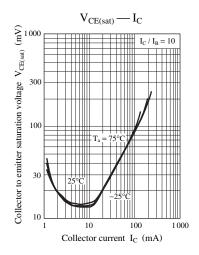
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

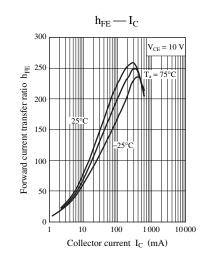
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---|----------------------|---|------|-----|------|------|
| Collector to base voltage | V_{CBO} | $I_C = 1 \mu A, I_E = 0$ | 30 | | | V |
| Collector to emitter voltage | V_{CEO} | $I_C = 1 \text{ mA}, I_B = 0$ | 20 | | | V |
| Emitter to base voltage | V_{EBO} | $I_E = 1 \mu A, I_C = 0$ | 5 | | | V |
| Collector cutoff current | I_{CBO} | $V_{CB} = 30 \text{ V}, I_{E} = 0$ | | | 1 | μΑ |
| Emitter cutoff current | I_{EBO} | $V_{EB} = 5 \text{ V}, I_{C} = 0$ | | | 1 | μΑ |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 5 \text{ V}, I_{C} = 50 \text{ mA}$ | 70 | | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_C = 50 \text{ mA}, I_B = 2.5 \text{ mA}$ | | | 80 | mV |
| Input resistance | R_1 | | -30% | 6.8 | +30% | kΩ |
| Resistance ratio | R_1/R_2 | | 0.8 | 1.0 | 1.2 | |
| ON-resistance * | R _{ON} | $V_{I} = 7 \text{ V}, R_{L} = 1 \text{ k}\Omega, f = 1 \text{ kHz}$ | | 1.1 | | Ω |
| Transition frequency | f_T | $V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$ | | 200 | | MHz |

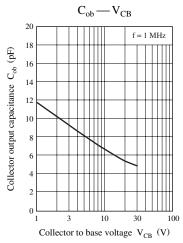


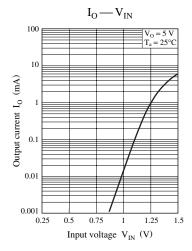


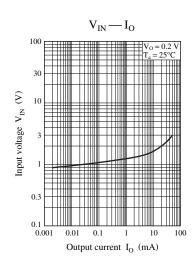












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